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Sheet 1

INFORMATION DISCLOSURE STATEMENT BY APPLICANT

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of 12 ·

U. S. PATENT DOCUMENTS Cite No.1 Publication Date Examiner **Document Number** Name of Patentee or Pages, Columns, Lines, Where Relevant Passages or Relevant Initials' Applicant of Cited Document Number-Kind Code² (F known) Figures Appear US-4,627,027 12/2/1986 TL Rai et al. ^{US-} 5,870,334 2/9/1999 Hemink et al. 76 US-5,949,714 9/7/1999 TL Hemink et al. US- 6,222,762 4/24/2001 Guterman et al. Tι ^{US-} 6,301,151 10/9/2001 Engh et al. TL US- 6,424,566 7/23/2002 Parker TI US- 6,522,580 2/18/2003 TL Chen et al. US- 6.525.964 2/25/2003 Tanaka et al. TL ^{US-} 6,529,412 3/4/2003 Chen et al. TL TL US- 20030147278 8/7/2003 Tanaka et al. US-US-US-US-บร-US-US US-US-

FOREIGN PATENT DOCUMENTS							
Examiner Initials*	Cite No. ¹	Foreign Patent Document	Publication Date	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages Or Relevant Figures Appear	те	
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INF	ORMATION	N DIS	CLOSURE	Filing Dat	October 20, 2003		
STATEMENT BY APPLICANT			PPLICANT	First Named Inventor	Chen		
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Sheet	2	of	2	Attorney Docket Number	SAND-01012US0		

•		NON PATENT LITERATURE DOCUMENTS	
Examiner Initials*	Cite No.1	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T ²
TL		Hosono, et al., A High Speed Failure Bit Counter for the Pseudo Pass Scheme (PPS) in Program Operation for Giga Bit NAND Flash, Toshiba Corporation, pp. 23-26.	
TL		Choi, et al., A Novel Booster Plate Technology in High Density NAND Flash Memories for voltage Scaling-down and Zero Progam Disturbance, Samsung electronics Co., LTD., pp. 238	
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